MP4313

45V, 3A, Low IQ, Synchronous Step-Down Converter with Frequency Spread Spectrum

DESCRIPTION

The MP4313 is a configurable-frequency, synchronous, step-down switching converter with integrated internal high-side and low-side power MOSFETs (HS-FET and LS-FET, respectively). It can achieve up to 3A of highly efficient output current (I_{OUT}) with current mode control for fast loop response.

The wide 3.3V to 45V input voltage (V_{IN}) range accommodates a variety of step-down applications in automotive input environments. High duty cycle and low-dropout mode are provided for automotive cold-crank conditions. The 1.7 μ A shutdown current (I_{SD}) allows the device to be used in battery-powered applications.

High power conversion efficiency across the entire load range is achieved by scaling down the switching frequency (f_{SW}) under light-load conditions. This reduces switching and gate driver losses.

An open-drain power good (PG) signal indicates whether the output is within 95% to 105% of its nominal voltage.

Frequency foldback prevents inductor current (IL) runaway during start-up. Thermal shutdown provides reliable, fault-tolerant operation.

The MP4313 is available in a QFN-20 (4mmx4mm) package.

FEATURES

- Wide 3.3V to 45V Operating Input Voltage (V_{IN}) Range
- Up to 3A Continuous Output Current (I_{OUT})
- 1.7μA Low Shutdown Current (I_{SD})
- 18μA Sleep Mode Quiescent Current (I_o)
- 48mΩ/20mΩ Internal Power MOSFETs
- 350kHz to 1000kHz Configurable Switching Frequency (f_{SW}) for Car Battery Applications
- Can Be Synchronized to an External Clock
- Out-of-Phase Synchronized Clock Output
- Frequency Spread Spectrum (FSS) for Low Electromagnetic Interference (EMI)
- Symmetric V_{IN} for Low EMI
- Power Good (PG) Output
- External Soft Start (SS)
- 100ns Minimum On Time $(t_{ON~MIN})$
- Selectable Advanced Asynchronous Modulation (AAM) Mode or Forced Continuous Conduction Mode (FCCM)
- Low-Dropout (LDO) Mode
- Over-Current Protection (OCP) with Hiccup Mode
- Available in a QFN-20 (4mmx4mm) Package
- Available in a Wettable Flank Package

APPLICATIONS

- Radios
- Battery-Powered Systems
- General-Purpose Consumer Applications
- Industrial Power Systems

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TYPICAL APPLICATION

ORDERING INFORMATION

* For Tape & Reel, add suffix -Z (e.g. MP4313GRE-Z).

** Moisture Sensitivity Level Rating

*** Wettable Flank

TOP MARKING (MP4313GRE-Z)

MPS: MPS prefix Y: Year code WW: Week code MP4313: Part number LLLLLL: Lot number E: Wettable flank

PACKAGE REFERENCE

PIN FUNCTIONS

ABSOLUTE MAXIMUM RATINGS (1)

ESD Ratings

Recommended Operating Conditions

Thermal Resistance θJA θJC QFN-20 (4mmx4mm) JESD51-7 (4)44.........9.... °C/W EVQ4313-R-00A (5)23.......2.5...°C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX) $-T_A$) / θ_{JA} . Exceeding the maximum allowable power dissipation can cause excessive die temperature, and the converter may go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) Operating junction temperatures above 125°C may be supported. Contact MPS for more details.
- 4) Measured on JESD51-7, 4-layer PCB. The values given in this table are only valid for comparison with other packages and cannot be used for design purposes. These values were calculated in accordance with JESD51-7, and simulated on a specified JEDEC board. They do not represent the performance obtained in an actual application.
- 5) Measured on the EVQ4313-R-00A (9cmx9cm), a 2oz copper thickness, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

VIN = 12V, VEN = 2V, TJ = -40°C to +125°C (6) **, typical values are at TJ = 25°C, unless otherwise noted.**

ELECTRICAL CHARACTERISTICS *(continued)*

VIN = 12V, VEN = 2V, TJ = -40°C to +125°C (6) **, typical values are at TJ = 25°C, unless otherwise noted.**

Notes:

6) Guaranteed by over-temperature correlation. Not tested in production.

7) Derived from bench characterization. Not tested in production.

TYPICAL CHARACTERISTICS

 V_{IN} = 12V, T_J = -40°C to +125°C, unless otherwise noted.

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TYPICAL CHARACTERISTICS *(continued)*

 V_{IN} = 12V, T_J = -40°C to +125°C, unless otherwise noted.

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TYPICAL CHARACTERISTICS *(continued)*

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 V_{IN} = 12V, T_J = -40°C to +125°C, unless otherwise noted.

TYPICAL PERFORMANCE CHARACTERISTICS

VIN = 12V, VOUT = 3.3V, L = 5.6µH, COUT = 94µF, fSW = 470kHz, TA = 25°C, unless otherwise noted. (8)

VIN = 12V, VOUT = 3.3V, L = 5.6µH, COUT = 94µF, fSW = 470kHz, TA = 25°C, unless otherwise noted. (8)

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VIN = 12V, VOUT = 3.3V, L = 5.6µH, COUT = 94µF, fSW = 470kHz, TA = 25°C, unless otherwise noted. (8)

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6 μ H, C_{OUT} = 94 μ F, f_{SW} = 470 k Hz, T_A = 25°C, unless otherwise **noted.** $^{(8)}$ $^{(9)}$

930 1000

VIN = 12V, VOUT = 3.3V, L = 5.6µH, COUT = 94µF, fSW = 470kHz, TA = 25°C, unless otherwise noted. (8) (9)

Notes:

8) Inductor part number: XAL6060-562MEB or XAL6060-562MEC; DCR = 14.5mΩ.

9) The EMC test results are based on the typical application circuit with EMI filters (see Figure 11 on page 33).

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6µH, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

1ms/div. 1ms/div.

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6µH, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

Shutdown through V_{IN}

Start-Up through EN $I_{\text{OUT}} = 0$ A, AAM mode

Start-Up through EN

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6µH, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6µH, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

 V_{IN} = 12V, V_{OUT} = 3.3V, $L = 5.6\mu$ H, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6µH, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

 V_{IN} = 12V, V_{OUT} = 3.3V, L = 5.6µH, f_{SW} = 470kHz, AAM mode, T_A = 25°C, unless otherwise noted.

FUNCTIONAL BLOCK DIAGRAM

Figure 1: Functional Block Diagram

TIMING SEQUENCE DIAGRAM

Figure 2: Timing Sequence Diagram

OPERATION

The MP4313 is a synchronous, step-down switching converter with integrated internal power MOSFETs. It can achieve up to 3A of highly efficient, continuous output current (I_{OUT}) with current mode control for fast loop response.

The device features a wide 3.3V to 45V input voltage (V_{IN}) range, configurable switching frequency (f_{SW}) , external soft start (SS) , and precision current limiting. Its low 1.7μA shutdown current (I_{SD}) makes it well-suited for batterypowered applications.

PWM Control

At moderate to high output currents, the MP4313 operates with a fixed frequency in peak current control mode to regulate the output voltage (V_{OUT}) . A pulse-width modulation (PWM) cycle is initiated by the internal clock. At the rising edge of the clock, the high-side power MOSFET (HS-FET) turns on and remains on until its current reaches the value set by the internal comparator (V_{COMP}) . The HS-FET remains on for a minimum of 100ns.

If the HS-FET is off, the low-side MOSFET (LS-FET) turns on and remains on until the next PWM cycle starts. The LS-FET remains on for a minimum of 80ns before the next cycle starts.

If the HS-FET current does not reach V_{COMP} within one PWM cycle, the HS-FET remains on to avoid shutting down the device. The HS-FET turns off after about 10µs, even if it has not reached V_{COMP}.

Light-Load Operation

The MP4313 has a mode selection pin (MODE) that selects the IC's operation mode at light loads. Under light-load conditions, the device can operate in either forced continuous conduction mode (FCCM) or advanced asynchronous modulation (AAM) mode.

If MODE is pulled above 1.8V, then the MP4313 operates in FCCM. The part works with fixed frequency from no load to full loads in this mode. Advantages of FCCM include the controllable fixed frequency and lower V_{OUT} ripple under lightload conditions.

If MODE is pulled below 0.4V, then the MP4313 operates in AAM mode. AAM mode optimizes

efficiency under light-load and no-load conditions.

If AAM mode is enabled, then the MP4313 first enters asynchronous operation as the inductor current $(I₁)$ approaches 0A (see Figure 3). If the load decreases further or if there is no load, V_{COMP} drops to its set value and the device enters AAM mode.

Figure 3: AAM Mode and FCCM

In AAM mode, the internal clock resets once V_{COMP} reaches its set value. The crossover time is used as the benchmark for the next clock. If the load increases and V_{COMP} exceeds its set value, then the device operates in discontinuous conduction mode (DCM) or FCCM, both of which have a constant f_{SW} .

Error Amplifier (EA)

The error amplifier (EA) compares the feedback (FB) voltage (V_{FB}) to the internal reference voltage (V_{REF}) (typically 0.815V), and outputs a current that is proportional to the difference between the two voltages. This I_{OUT} charges the compensation network to set V_{COMP} , which controls the power MOSFET's current.

During normal operation, the minimum V_{COMP} is 0.9V, and the maximum is 2V. If the IC shuts down, V_{COMP} is pulled down to AGND internally.

Internal Regulator (VCC)

The 4.9V internal regulator (VCC) powers most of the internal circuitry. The regulator uses the VIN pin as its input and operates across the entire V_{IN} range. If V_{IN} exceeds 4.9V, then VCC is in full regulation. If V_{IN} drops below 4.9V, then VCC's output degrades.

Bootstrap (BST) Charging

The internal bootstrap (BST) regulator charges and regulates the BST capacitor (C_{BST}) to about 5V. If the difference between the BST and SW

Pin voltages (V_{BST} - V_{SW}) drops below 5V, then a P-channel MOSFET pass transistor connected between the VCC and BST pins turns on to charge C_{BST} . The external circuit should provide enough voltage headroom to facilitate charging. If the HS-FET turns on, then V_{BST} exceeds the VCC voltage (V_{CC}) and C_{BST} cannot be charged.

At high duty cycles, there is less time to charge C_{BST} . This means that C_{BST} may not be charged sufficiently. If the external circuit has an insufficient voltage or not enough time to charge C_{BST} , then an additional external circuit is required to ensure that V_{BST} remains within its normal operation range.

Low-Dropout Mode and BST Refresh

To improve dropout, the MP4313 is designed to operate at close to 100% duty cycle as long as the BST-to-SW pin voltage is above 2.5V. When the voltage from BST to SW drops below 2.5V, the HS-FET is turned off using a UVLO circuit, which allows the LS-FET to conduct and refresh the charge on the BST capacitor. In DCM mode or PSM mode, the LS-FET is forced on to refresh the BST voltage.

Since the supply current sourced from the BST capacitor is low, the HS-FET can remain on for more switching cycles than are required to refresh the capacitor. Thus, the effective duty cycle of the switching regulator is high.

The effective duty cycle during regulator dropout is mainly influenced by the voltage drops across the power MOSFET, the inductor resistance, the low-side diode, and the PCB resistance.

Enable (EN) and Under-Voltage Lockout (UVLO) Protection

The enable (EN) pin is a digital control pin that turns the converter on and off.

Enable via External Logic High/Low Signal

Pull EN above 1V to turns the converter on; pull EN below 0.85V to turn it off.

Configurable VIN UVLO Protection

If V_{IN} exceeds the UVLO rising threshold, then the IC can be enabled and disabled via the EN pin. A configurable V_{IN} UVLO threshold and hysteresis can be generated. The EN voltage (V_{EN}) can be set via resistor dividers (R_{EN1} + R_{EN2}) (see Figure 4).

Figure 4: Enable Divider Circuit

Configurable Switching Frequency (f_{SW}) and Frequency Foldback

f_{sw} can be configured via an external resistor (R_{FREQ}) connected between the FREQ pin and AGND, or by a logic-level SYNC signal.

See the f_{SW} vs. R_{EBEQ} curves on page 13 to select R_{FREQ} and set f_{SW}. If f_{SW} is set high, it may fold back at high input voltages to avoid triggering the minimum on time $(t_{ON~MIN})$ and forcing the output out of regulation.

Set f_{SW} between 350kHz and 1000kHz for car battery applications. Table 1 lists the recommended R_{FREQ} values for common switching frequencies. High frequencies can be used in applications that do not require a critical f_{SW} limit or that have a low, stable V_{IN} .

Table 1: RFREQ vs. fSW

Frequency Spread Spectrum (FSS)

The MP4313 employs a 12kHz modulation frequency and a fixed 128-step triangular profile to spread the internal f_{SW} across a 20% ($\pm 10\%$) window (see Figure 5 on page 27). The steps are fixed and independent of the set f_{SW} . This optimizes the frequency spread spectrum (FSS) performance.

Figure 5: Spread Spectrum Scheme

Side bands are created by modulating f_{SW} via the triangle modulation waveform. This reduces the fundamental f_{SW} emission power and harmonics, which reduces noise caused by peak electromagnetic interference (EMI).

Soft Start (SS)

The MP4313 implements soft start (SS) to prevent V_{OUT} from overshooting during start-up.

Once SS is initiated, an internal current source charges the external soft-start capacitor (C_{ss}) . If the soft-start voltage (V_{SS}) drops below V_{REF} , then V_{SS} overrides V_{REF} and the EA uses V_{SS} as the reference. If V_{SS} exceeds V_{REF} , then the EA uses VREF as the reference.

The soft-start capacitance (C_{SS}) can be calculated with Equation (1):

$$
C_{SS}(nF) = \frac{t_{SS}(ms) \times I_{SS}(\mu A)}{V_{REF}(V)} = 6.25 \times t_{SS}(ms) \quad (1)
$$

The SS pin can be used for tracking and sequencing.

Pre-Biased Start-Up

If V_{FB} exceeds V_{SS} - 150mV during start-up, then the output has a pre-biased voltage. With a prebiased voltage, the HS-FET and LS-FET do not turn on until V_{SS} exceeds V_{FB} .

Thermal Shutdown

Thermal shutdown prevents the IC from operating at exceedingly high temperatures. If the die temperature exceeds the thermal shutdown threshold (about 170°C), then the device shuts down. Once the temperature drops below about 150°C, the device initiates a new SS and resumes normal operation.

Current Comparator and Current Limit

The MOSFET currents are sensed via a currentsense MOSFET. This current is fed to the highspeed current comparator for current mode control. The current comparator uses this sensed current as one of its inputs.

If the HS-FET turns on, the comparator is blanked until the end of the turn-on period to mitigate noise. The comparator compares the MOSFET current to the set V_{COMP} value. If the sensed current exceeds V_{COMP} , then the comparator outputs low to turn off the HS-FET. The internal MOSFET maximum current is limited internally cycle by cycle.

Output Over-Voltage Protection (OVP) with Hiccup Mode

If an output short to ground occurs, V_{OUT} may drop below 70% of its nominal value. If this occurs, the MP4313 shuts down to discharge C_{SS} . Once C_{SS} is discharged, the device initiates a SS to resume normal operation. This process repeats until the fault condition is removed.

Start-Up and Shutdown

If both V_{IN} and V_{EN} exceed their respective thresholds, the MP4313 starts up. The reference block starts up first to generate a stable V_{REF} and currents. Then the internal regulator starts up to provide a stable supply for the remaining circuitries.

While the internal supply rail is up, an internal timer turns the HS-FET and LS-FET off for about 50µs to blank any start-up glitches. Once the soft-start block is enabled, the device outputs low to ensure that the remaining circuitry is ready before slowly ramping up.

Three events can shut down the IC: V_{EN} going low, V_{IN} going low, and thermal shutdown. Once shutdown is initiated, the signaling path is blocked to avoid triggering any faults. Then V_{COMP} and the internal supply rail are pulled down. The floating driver is not subject to this shutdown command, but its charging path is disabled.

Power Good (PG) Output

The power good (PG) pin is an open-drain output. If using the PG pin, connect it to a power source via a pull-up resistor. If V_{OUT} is between 95% and 105% of the nominal voltage, then PG is pulled high. If V_{OUT} exceeds 106.5% or drops below 93.5% of the nominal voltage, then PG is pulled low.

SYNCIN and SYNCO

 f_{SW} can be synchronized to the rising edge of the SYNCIN clock. It is recommended that the SYNCIN frequency (f_{SYNCIN}) be between 350kHz and 1000kHz. SYNCIN's off time (t_{OFF}) should be shorter than the internal oscillator period; otherwise, the internal clock may turn on the HS-FET before the rising edge of SYNCIN.

There is no SYNCIN pulse width limit; however, there is always parasitic capacitance on the pad. If the pulse width is too short, then a clear rising and falling edge may not be achieved due to the parasitic capacitance. It is recommended to set the pulse width above 100ns.

If using SYNCIN in AAM mode, pull SYNCIN below 0.4V or float SYNCIN before start-up and then add the external SYNCIN clock. Connect a 10kΩ to 51kΩ resistor between SYNCIN and AGND to avoid floating SYNCIN.

The SYNCO pin provides a default 180° phaseshifted clock for the internal oscillator. If there is not an external SYNCIN clock, then SYNCO provides a 180° phase-shifted clock that is compared to the internal clock. If there is an external SYNCIN clock, then SYNCO provides a 180° phase-shifted clock that is compared to the external SYNCIN clock.

APPLICATION INFORMATION

Setting the Output Voltage

The external resistor divider connected to the FB pin sets V_{OUT} (see Figure 6).

Figure 6: Feedback Network

The feedback resistance (R_{FB2}) can be calculated with Equation (2):

$$
R_{FB2} = \frac{R_{FB1}}{\frac{V_{OUT}}{0.815V} - 1}
$$
 (2)

Table 2 lists the recommended feedback resistor values for common output voltages.

Table 2: Recommended Resistor Values for Common Output Voltages

Selecting the Input Capacitor (CIN)

The step-down converter has a discontinuous input current, and requires a capacitor to supply AC current to the converter while maintaining the DC V_{IN}. For the best performance, use low-ESR capacitors. Ceramic capacitors with X5R or X7R dielectrics are highly recommended due to their low ESR and small temperature coefficients. For most applications, a 4.7µF to 10µF capacitor is sufficient. It is strongly recommended to use another, lower-value capacitor (0.1µF) with a small package size (0603) to absorb highfrequency noise. Place the smaller capacitor as close to the VIN pin and PGND as possible.

Since the input capacitor (C_{IN}) absorbs the input switching current, it requires an adequate ripple current rating. Estimate the RMS current in C_{IN} (I_{CIN}) with Equation (3):

$$
I_{\text{CIN}} = I_{\text{LOAD}} \times \sqrt{\frac{V_{\text{OUT}}}{V_{\text{IN}}} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}})}
$$
(3)

The worst-case condition occurs at $V_{IN} = 2 \times$ V_{OUT} , which can be calculated with Equation (4):

$$
I_{\text{CIN}} = \frac{I_{\text{LOAD}}}{2} \tag{4}
$$

For simplification, choose a C_{IN} with an RMS current rating greater than half of the maximum load current (I_{LOAD MAX}).

 C_{IN} can be electrolytic, tantalum, or ceramic. If using electrolytic or tantalum capacitors, place a small, high-quality ceramic capacitor (0.1μF) as close to the device as possible.

The input capacitance determines the input voltage ripple of the converter. If using ceramic capacitors, ensure that C_{IN} meets the system design's input voltage ripple (ΔV_{IN}) requirement. When using ceramic capacitors, ensure that they have enough capacitance to provide a sufficient charge to prevent an excessive voltage ripple at the input. The input voltage ripple (ΔV_{IN}) caused by the capacitance can be estimated with Equation (5):

$$
\Delta V_{\text{IN}} = \frac{I_{\text{LOAD}}}{f_{\text{SW}} \times C_{\text{IN}}} \times \frac{V_{\text{OUT}}}{V_{\text{IN}}} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}})
$$
(5)

Selecting the Output Capacitor (C_{OUT})

The output capacitor (C_{OUT}) maintains the DC V_{OUT}. Use ceramic, tantalum, or low-ESR electrolytic capacitors. Ceramic capacitors with low ESR are recommended for their small size and low output voltage ripple. The output voltage ripple (ΔV_{OUT}) can be calculated with Equation (6):

$$
\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{f_{\text{SW}} \times L} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}) \times (R_{\text{ESR}} + \frac{1}{8 \times f_{\text{SW}} \times C_{\text{OUT}}}) \text{ (6)}
$$

Where L is the inductance, and R_{ESR} is the equivalent series resistance of C_{OUT} .

For ceramic capacitors, the capacitance dominates the impedance at f_{SW} and causes the majority of ΔV_{OUT} . For simplification, the output voltage ripple (ΔV_{OUT}) can be estimated with Equation (7):

$$
\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{8 \times f_{\text{SW}}^2 \times L \times C_{\text{OUT}}} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}})
$$
 (7)

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For tantalum or electrolytic capacitors, the ESR dominates the impedance at f_{SW} . For simplification, ΔV_{OUT} can be estimated with Equation (8):

$$
\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{f_{\text{SW}} \times L} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}) \times R_{\text{ESR}} \tag{8}
$$

The characteristics of C_{OUT} also affect the stability of the regulation system. The MP4313 can be optimized for a wide range of capacitances and ESR values.

Selecting the Inductor

For most applications, a 1µH to 10µH inductor with a DC current rating of at least 25% greater than $I_{\text{LOAD MAX}}$ is recommended. For higher efficiency, choose an inductor with a lower DC resistance. A larger-value inductor offers less ripple current and a lower ΔV_{OUT} ; however, a larger-value inductor also has a larger physical size, higher series resistance, and lower saturation current. A good rule to determine the inductance is to allow the inductor ripple current (ΔI_L) to be approximately 30% of $I_{LOAD MAX}$. Estimate the inductance (L) with Equation (9):

$$
L = \frac{V_{\text{OUT}}}{f_{\text{SW}} \times \Delta I_L} \times (1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}})
$$
(9)

Choose ΔI_L to be about 30% of $I_{LOAD MAX}$. The maximum inductor peak current (I_{LP}) can be calculated with Equation (10):

$$
I_{LP} = I_{LOAD} + \frac{V_{OUT}}{2 \times f_{SW} \times L} \times (1 - \frac{V_{OUT}}{V_{IN}})
$$
 (10)

Setting the VIN Under-Voltage Lockout (UVLO) Threshold

The MP4317 has an internal, fixed UVLO threshold. The rising threshold is 3V, and the falling threshold is about 2.7V. For applications that require a higher UVLO, place an external resistor divider between the VIN and EN pins to raise the UVLO threshold (see Figure 7).

The UVLO rising threshold (V_{IN} UVLO RISING) can be calculated with Equation (11):

$$
V_{\text{IN_UVLO_RISING}} = (1 + \frac{R_{\text{UP}}}{R_{\text{DOWN}}}) \times V_{\text{EN_RISING}} \ \, (11)
$$

Where $V_{EN-RISING}$ is 1V.

Figure 7: Adjustable UVLO Using EN Divider

The UVLO falling threshold $(V_{IN}$ UVLO FALLING) can be calculated with Equation (12):

$$
V_{IN_UVLO_FALLING} = (1 + \frac{R_{UP}}{R_{DOWN}}) \times V_{EN_FALLING}
$$
 (12)

Where V_{EN} $FALLING$ is 0.85V.

Selecting the External Bootstrap (BST) Diode and Resistor

An external BST diode can enhance the BST regulator's efficiency during high duty cycles. A 2.5V to 5V power supply can be used to power the external BST diode. It is recommended to use V_{CC} or V_{OUT} as the power supply (see Figure 8).

Figure 8: Optional External BST Diode for Enhanced Efficiency

It is recommended to use an IN4148 external BST diode. A resistor (R_{BST}) in series with C_{BST} can reduce the V_{SW} rising slew rate and voltage spikes. This reduces EMI and voltage stress at a high input voltages. A higher resistance is better for SW spike reduction, but can compromise efficiency. To make a tradeoff between EMI and efficiency, it is recommended to keep R_{BST} below 20 Ω . The recommended C_{BST} value is 0.1µF to 1μF.

Selecting the VCC Capacitor (C_{VCC})

The VCC capacitance (C_{VCC}) should be 10 times the boost capacitor's capacitance. C_{VCC} should not exceed 68µF.

MP4313 – 45V, 3A, LOW-IQ, SYNCHRONOUS STEP-DOWN CONVERTER WITH FSS

PCB Layout Guidelines (10)

Efficient PCB layout is critical for stable operation. It is recommended to use a 4-layer layout to improve thermal performance. For the best results, refer to Figure 9 and follow the guidelines below:

- 1. Place the symmetric input capacitors as close to VIN and PGND as possible.
- 2. Connect a large copper plane directly to PGND.
- 3. If the bottom PCB layer is the ground plane, place multiple vias near PGND.
- 4. Use short, direct, and wide traces for the high-current paths connected to VIN and PGND.
- 5. Place the input capacitor as close to the VIN and PGND pins as possible to minimize high-frequency noise. It is recommended that C_{IN} be a ceramic bypass capacitor in a small 0603 package.
- 6. Keep the connection between the input capacitor and VIN as short and wide as possible.
- 7. Place the VCC capacitor as close to VCC and AGND as possible.
- 8. Route the SW and BST traces away from sensitive analog areas, such as FB.
- 9. Keep the FB trace as short as wide as possible by placing the FB resistors close to the IC.
- 10. Use multiple vias to connect the power planes and the internal layers.

Note:

10) The recommended PCB layout is based on Figure 10 on page 32.

Top Layer

Mid-Layer 1

Mid-Layer 2

Bottom Layer Figure 9: Recommended PCB Layout

TYPICAL APPLICATION CIRCUITS

Figure 10: Typical Application Circuit (V_{OUT} = 5V, f_{SW} = 470kHz)

TYPICAL APPLICATION CIRCUITS *(continued)*

Figure 11: Typical Application Circuit with EMI Filters ($V_{\text{OUT}} = 3.3V$ **,** $f_{\text{SW}} = 470$ **kHz)**

QFN-20 (4mmx4mm) Wettable Flank

PACKAGE INFORMATION

TOP VIEW

SIDE VIEW

SECTION A-A

RECOMMENDED LAND PATTERN

NOTE:

1) THE LEAD SIDE IS WETTABLE. 2) ALL DIMENSIONS ARE IN MILLIMETERS. 3) LEAD COPLANARITY SHALL BE 0.08 MILLIMETERS MAX. 4) JEDEC REFERENCE IS MO-220. 5) DRAWING IS NOT TO SCALE.

CARRIER INFORMATION

Note:

11) N/A indicates "not available" in tubes. For 500-piece tape & reel prototype quantities, contact MPS. (The order code for a 500-piece partial reel is "-P". Tape & reel dimensions are the same as for full reel.)

REVISION HISTORY

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